

Cite this: DOI: 00.0000/xxxxxxxxxx

Supplementary Information – Single-photon ionization of SiC in the gas phase: experimental and *ab initio* characterizations of SiC⁺

B. Gans,^{*a} J. Liévin,^b P. Halvick,^c N. L. Chen,^a S. Boyé-Péronne,^a S. Hartweg,^{d‡} G.A. Garcia,^d and J.C. Loison^c

Received Date
Accepted Date

DOI: 00.0000/xxxxxxxxxx

1 Effect of the core and core-valence correlation and of the basis set on the 1⁺2⁺Π electronic state potential energy curve

In this section, we discuss the 1⁺2⁺Π double well shape, when going from *V*/AV5Z to *CV*/ACV6Z calculations. As shown in the left panel of Figure S1, the lowest minimum moves from the larger internuclear distance (1.94 Å) to the smaller one (1.74 Å). As a consequence the lowest vibrational levels are shifted to lower energies and the maximum vibrational overlaps occur at shorter distances, *i.e.* closer to the minima of the X and a states of SiC. The result of these changes on the calculated photoelectron spectra is illustrated in the right panels of Figure S1. Apart from a slight red shift of about 40 meV of both transitions, this does not change our conclusion in the main paper concerning a "matching" with the experimental photoelectron spectrum for the 1⁺2⁺Π ← X³Π transition, and an "unmatching" for the 1⁺2⁺Π ← a¹Σ⁺ transition.

2 Procedure used for estimating the photoionization probabilities

Table S1 gives, for the different states of SiC and SiC⁺, the weights *w* of the main configurations involved in single electron ionization processes. These weights correspond to the squares of the CI coefficients of the considered configurations in the MRCI/AV5Z wave functions obtained at *R* = 1.72 Å, close to the

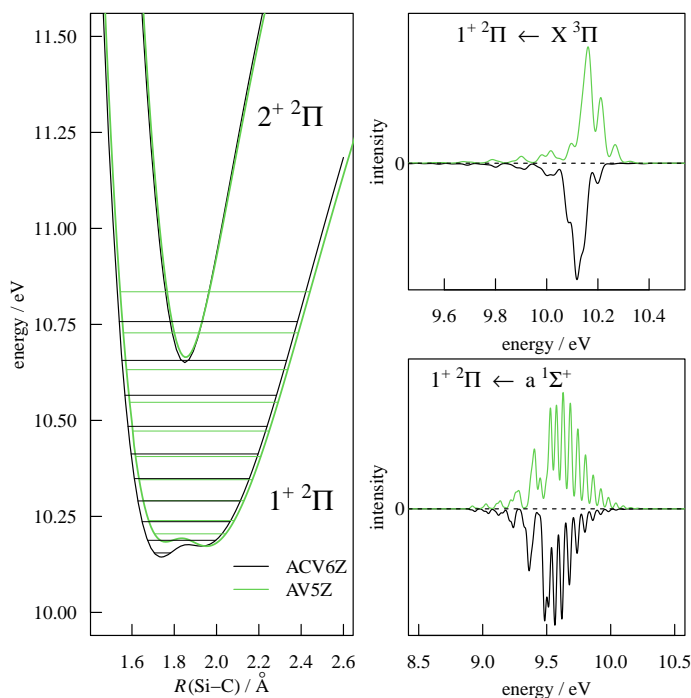


Fig. S1 On the left side, potential energy curves of the first two 2⁺Π states of SiC⁺ computed at the MRCI+Q/AV5Z (in green) and MRCI+Q/ACV6Z (in black) levels of theory. On the right side, corresponding calculated photoelectron spectra for the 1⁺2⁺Π ← X³Π and 1⁺2⁺Π ← a¹Σ⁺ transitions using the same color code.

* Corresponding author: berenger.gans@universite-paris-saclay.fr

^a Institut des Sciences Moléculaires d'Orsay, CNRS, Université Paris-Saclay, F-91405 Orsay, France

^b Spectroscopy, Quantum Chemistry and Atmospheric Remote Sensing, Université Libre de Bruxelles, CP 160/09, B-1050 Bruxelles, Belgium

^c Institut des Sciences Moléculaires, CNRS, Université de Bordeaux, F-33400 Talence, France

^d Synchrotron SOLEIL, L'Orme des Merisiers, St. Aubin, F-91192 Gif sur Yvette, France
‡ current address: Institute of Physics, University of Freiburg, 79104 Freiburg, Germany

ground state geometry of SiC. Let us note that in the case of the $2^+2\Pi$ state, the main configuration with $w= 0.77$ does not obey the single electron ejection condition, and does not therefore contribute to the photoionization. The secondary configuration obeys the condition, but with a negligible weight.

The probabilities P of the photoionizing transitions are provided in Table S2. They are given by the formula: $P = w_n \cdot w_c \cdot g_n \cdot g_c$, where w_n and w_c are the weights for the neutral and the cation, respectively, and g_n and g_c are the corresponding degeneracies, including the orbital and spin contributions. $P_{\text{norm.}}$ are the probabilities normalized with respect to the main $X^+4\Sigma^- \leftarrow X^3\Pi$ photoionizing transition.

Table S1 Main configurations and their corresponding weights (w) for the different states of SiC and SiC⁺ involved in photoionizing transitions implying single electron ejection.

State	w	Main configuration
$X^3\Pi$	0.77	[...]7 σ^1 2 π^3
$a^1\Sigma^+$	0.71	[...]7 σ^0 2 π^4
$X^+4\Sigma^-$	0.87	[...]7 σ^1 2 π^2
$1^+2\Delta$	0.85	[...]7 σ^1 2 π^2
$1^+2\Pi$	0.71	[...]7 σ^0 2 π^3
$1^+2\Sigma^-$	0.86	[...]7 σ^1 2 π^2
$1^+2\Sigma^+$	0.82	[...]7 σ^1 2 π^2
$2^+2\Pi$	0.77*	[...]7 σ^2 2 π^1 *
	0.04	[...]7 σ^0 2 π^3

* The main configuration does not lead to ionization (see text).

Table S2 Pertinent parameters for the photoionization probabilities of each photoionizing transitions used in the calculated photoelectron spectrum of Fig. 5 of the main paper.

Transitions	w_n	w_c	g_n	g_c	P	$P_{\text{norm.}}^*$
$X^+4\Sigma^- \leftarrow X^3\Pi$	0.77	0.87	6	4	16.2	1.0
$1^+2\Delta \leftarrow X^3\Pi$	0.77	0.85	6	4	15.8	1.0
$1^+2\Pi \leftarrow X^3\Pi$	0.77	0.71	6	4	13.2	0.8
$1^+2\Sigma^- \leftarrow X^3\Pi$	0.77	0.86	6	2	8.0	0.5
$1^+2\Sigma^+ \leftarrow X^3\Pi$	0.77	0.82	6	2	7.6	0.5
$2^+2\Pi \leftarrow X^3\Pi$	0.77	0.04	6	4	0.8	0.0
$1^+2\Pi \leftarrow a^1\Sigma^+$	0.71	0.71	1	4	2.0	0.1

* Normalized probability.